



HIGH-CAPACITY NANOSTRUCTURED SILICON...

Jason Graetz *et al.*

Appl. No.:10/660,382 Atty. Docket:CTJPL.008A

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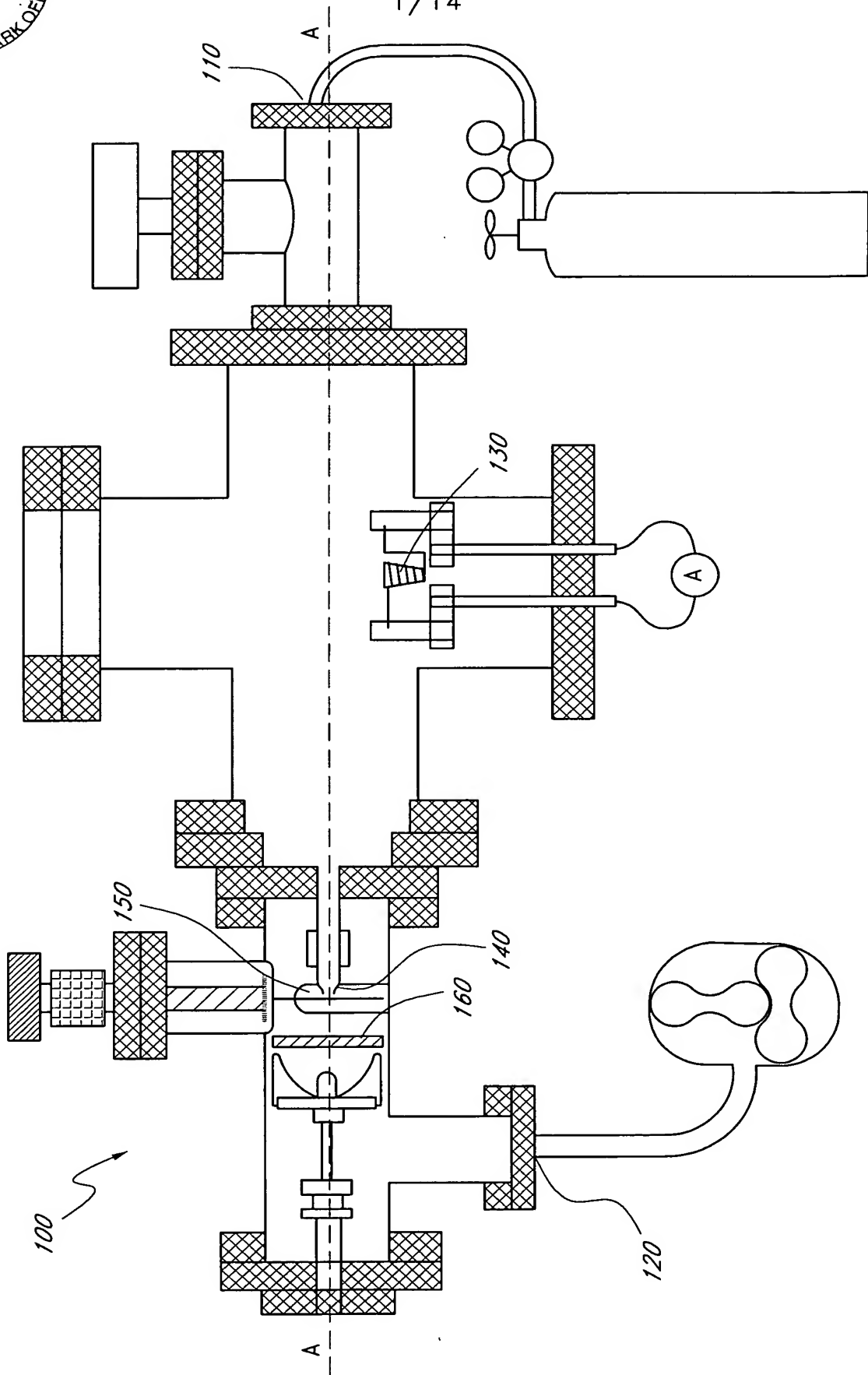


FIG. 1

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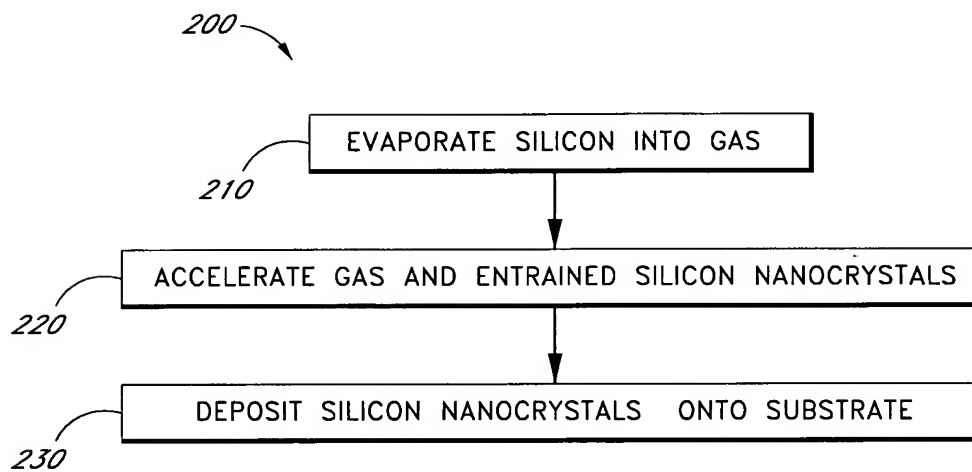


FIG.2

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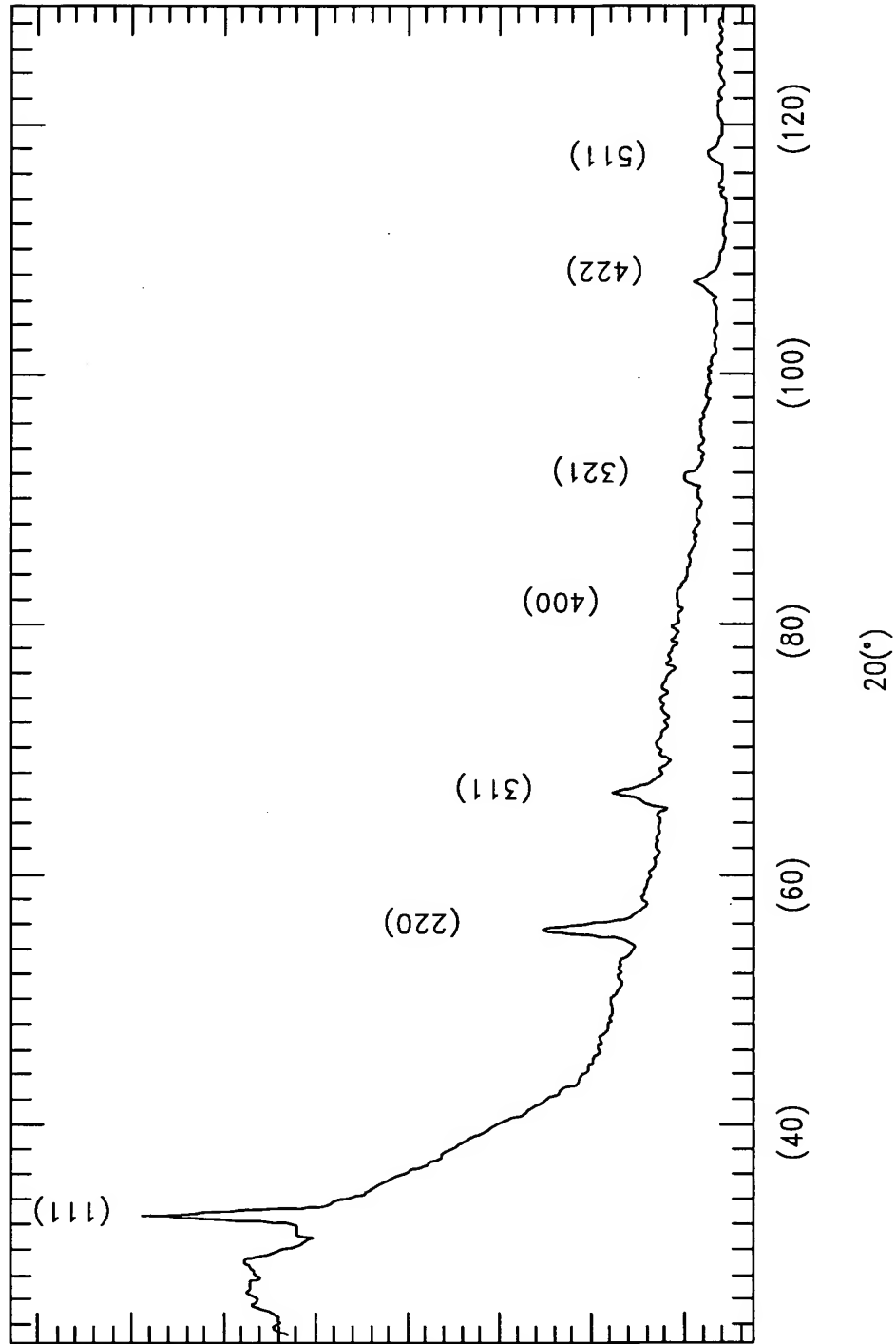


FIG. 3

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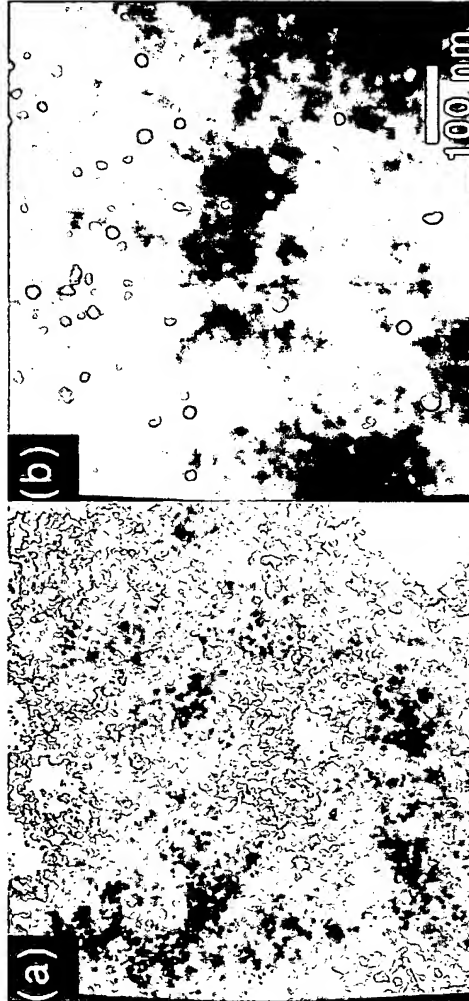


FIG. 4B

FIG. 4A

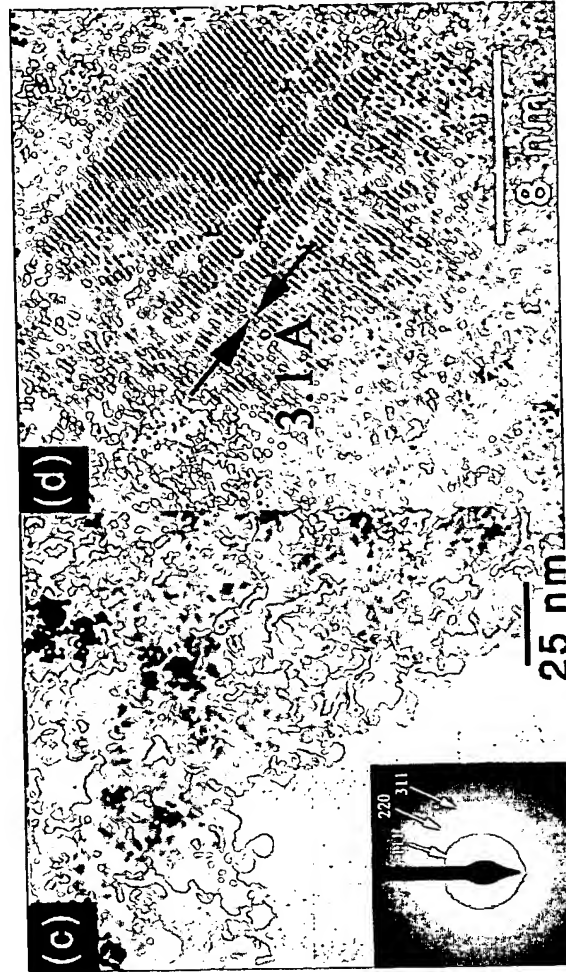


FIG. 4D

FIG. 4C

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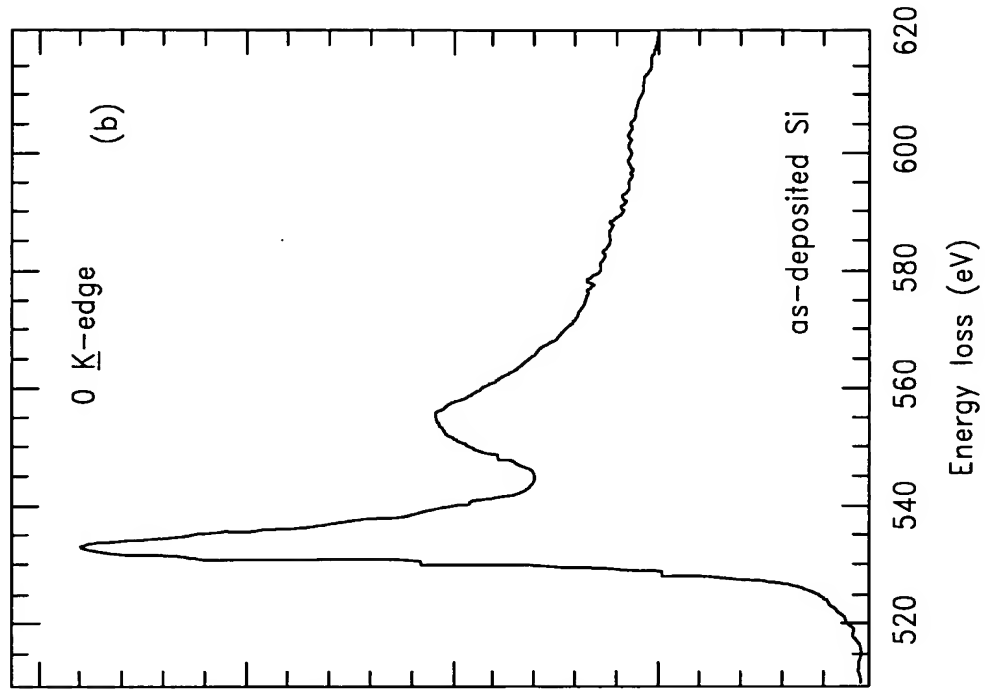


FIG. 5B

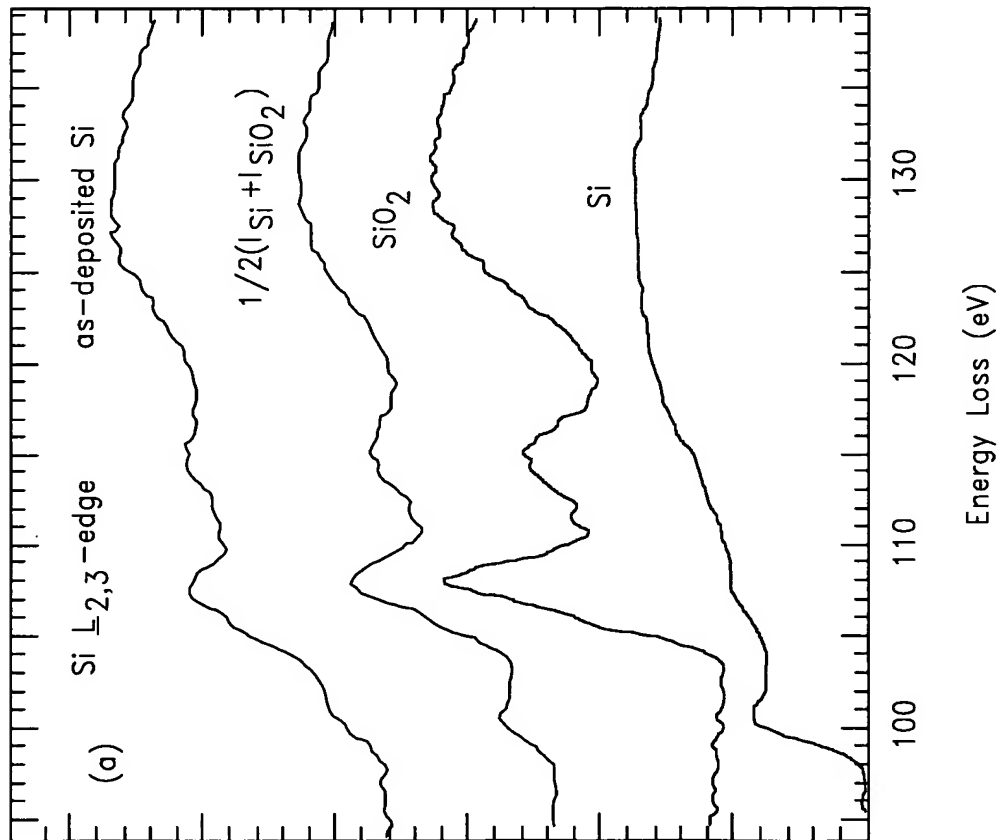


FIG. 5A

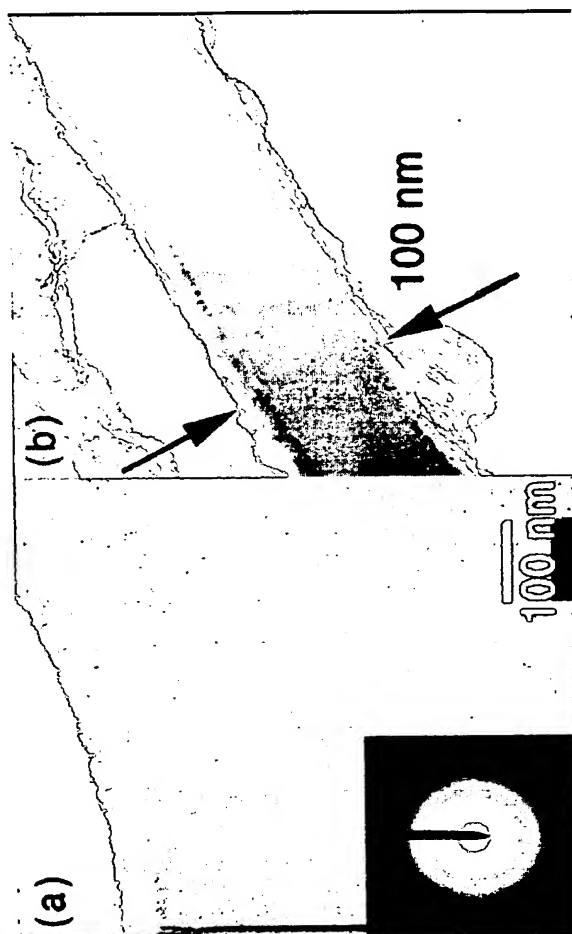


FIG. 6B

FIG. 6A



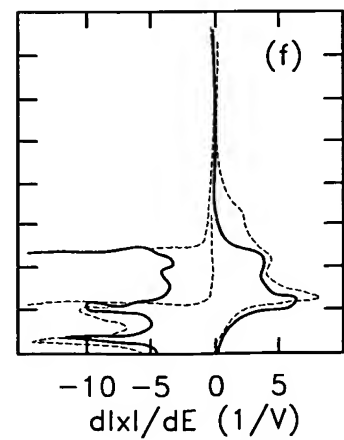
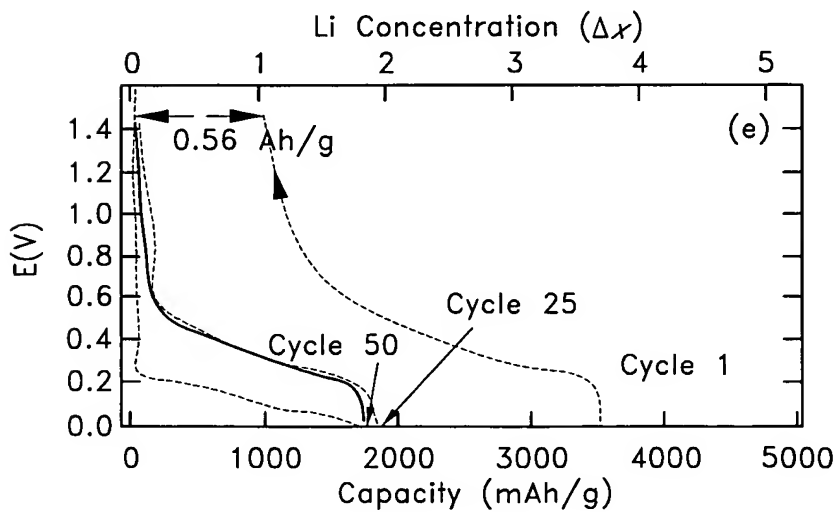
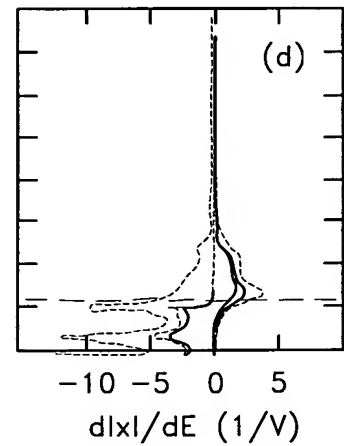
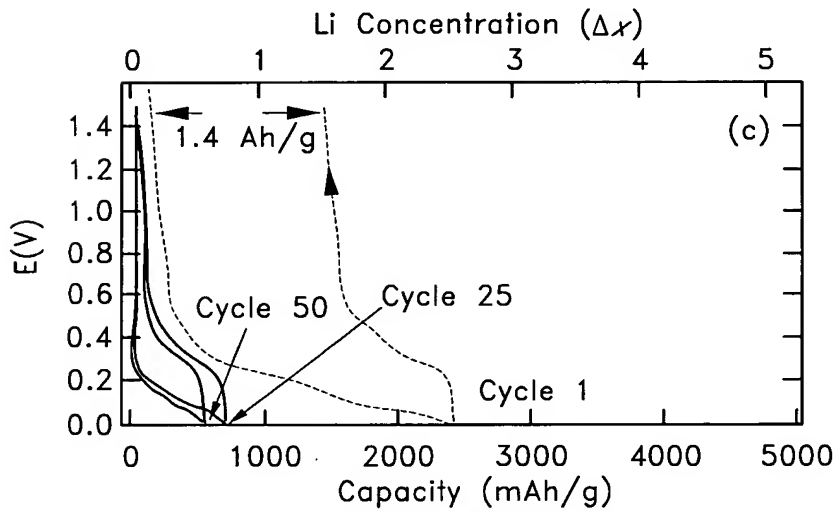
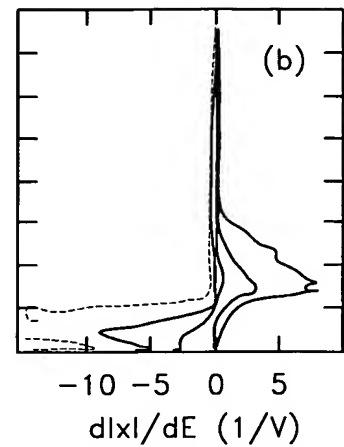
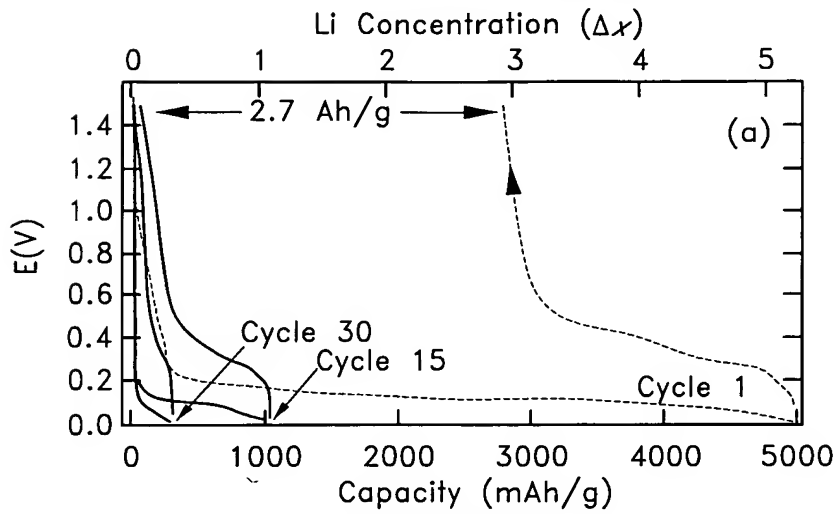
FIG. 7A

FIG. 7B

FIG. 7C



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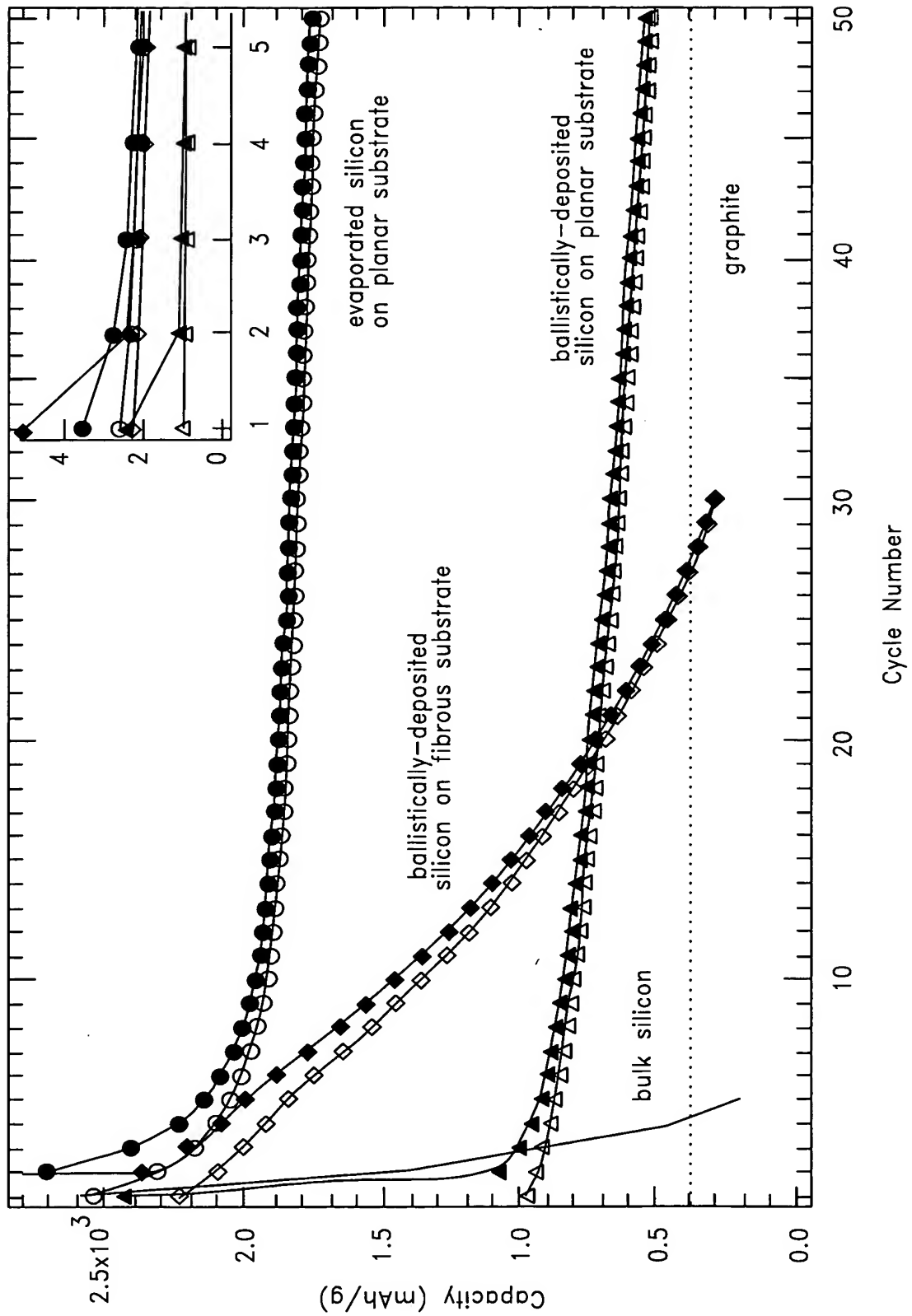
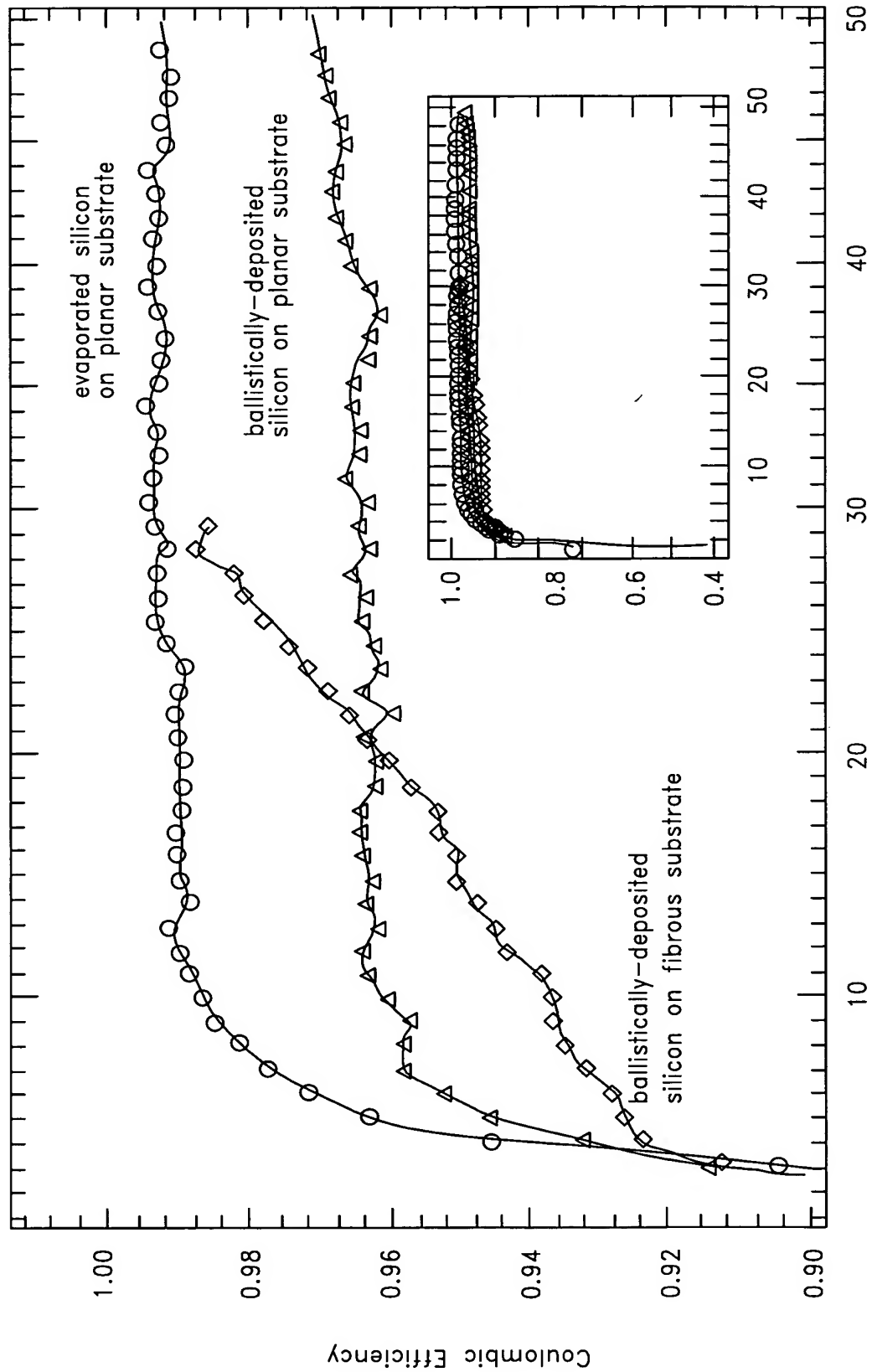


FIG.9



Cycle Number

FIG. 10

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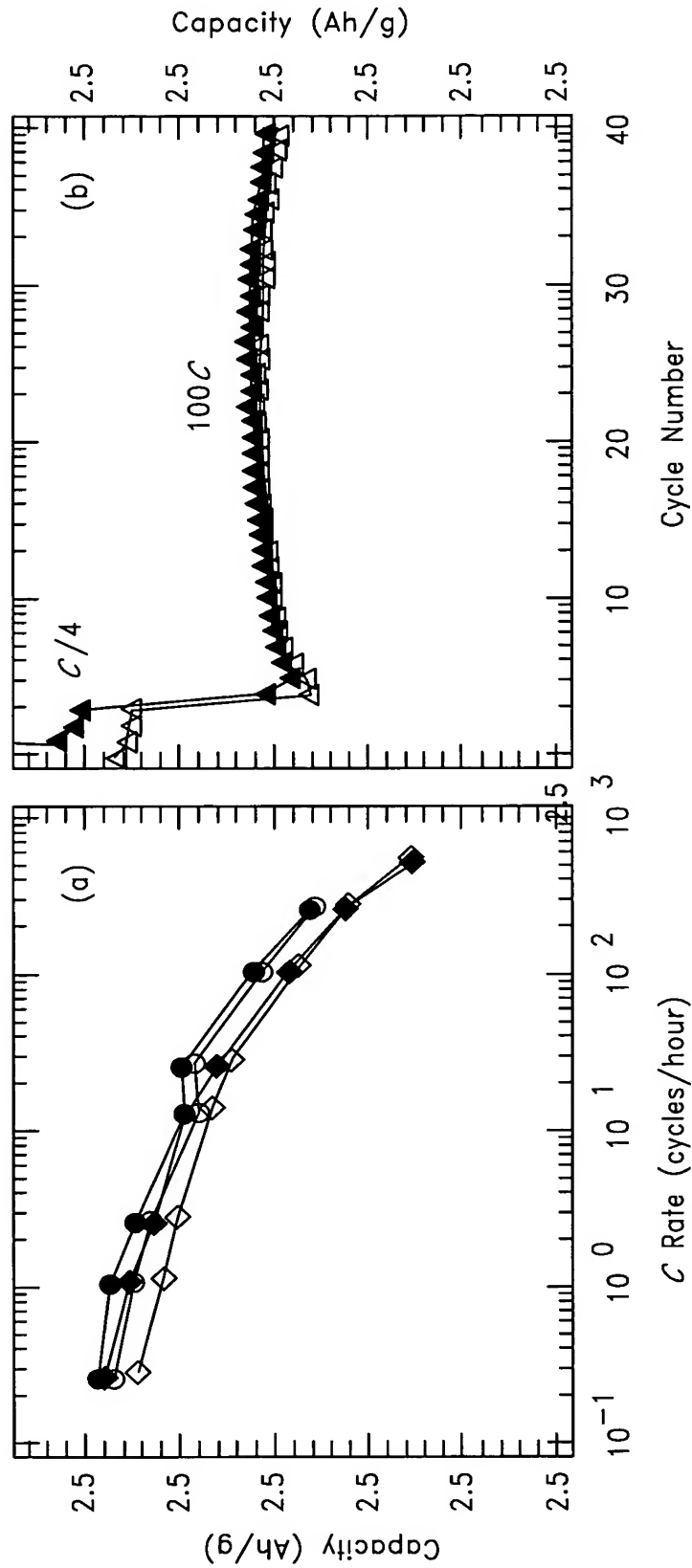


FIG. 11B

FIG. 11A

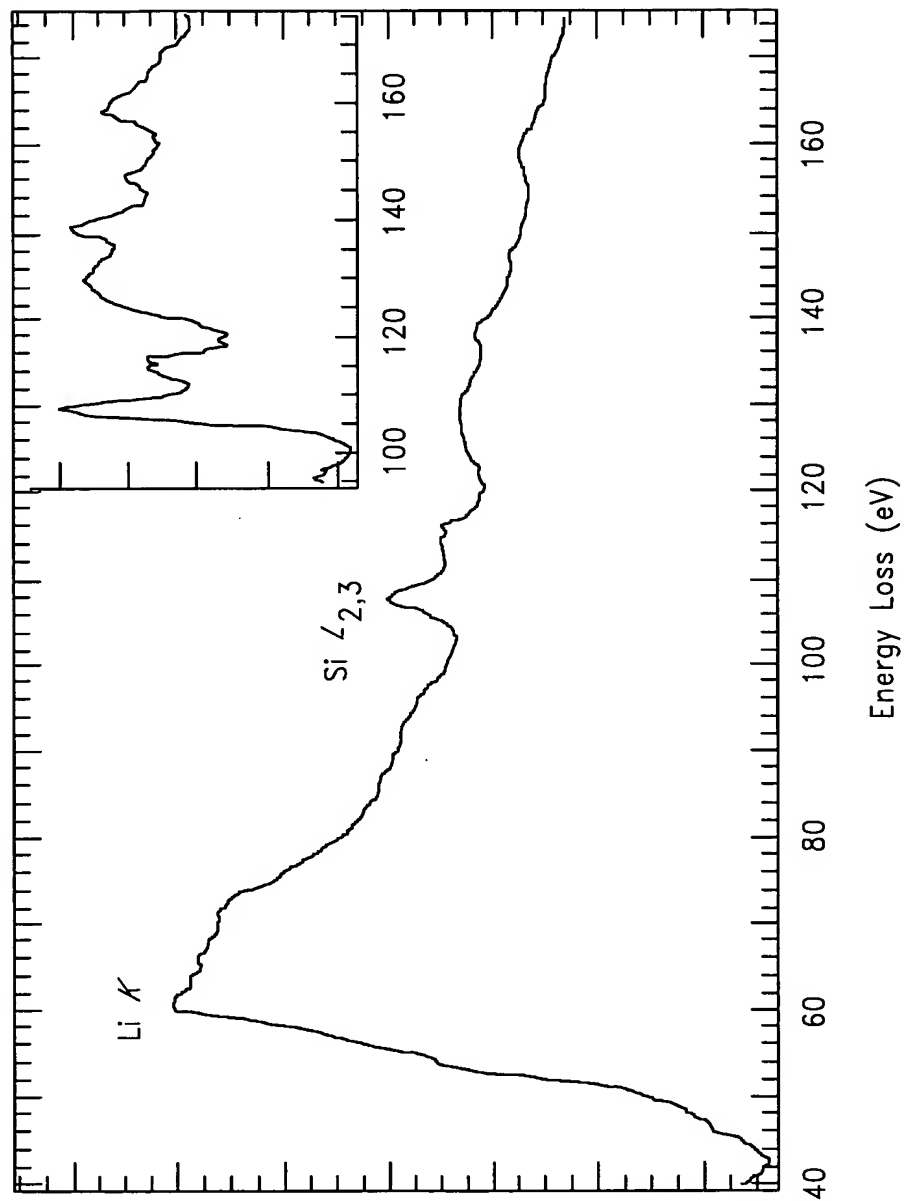


FIG. 12

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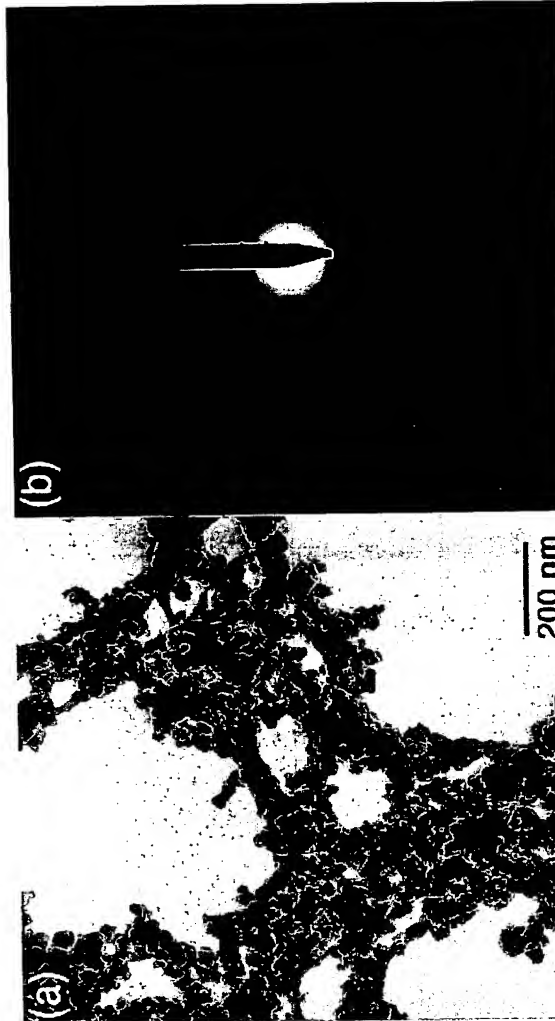


FIG. 13B

FIG. 13A